

 $V_{RRM}$  = 1200V

 $I_{F (Nominal)} = 40A$ 

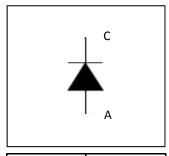
 $T_{J \text{ (max)}} = 150^{\circ}\text{C}$ 

 $V_F typ = 2.3V$ 

## **Applications**

- Industrial Motor Drive
- Uninterruptible Power Supply
- Welding
- Solar Inverter





С	Α
Cathode	Anode

Features -	→ Benefits
Low V <sub>F</sub>	High efficiency in a wide range of applications
Ultra Fast-Soft Recovery	Performance optimized for IGBT anti parallel diode

Chip Type	$V_{RRM}$	I <sub>F(Nominal)</sub>	Die Size	Package Type	
IRD3CH24DB6	1200V	40A	4.293 x 5.588mm <sup>2</sup>	Wafer	

#### **Mechanical Parameters**

Die Size	4.293 x 5.588				
Anode Pad Size	2.844 x 4.135	mm <sup>2</sup>			
Area Total / Active	24.0/14.1				
Thickness	330	μm			
Wafer Size	150	mm			
Minimum Street Width	100	μm			
Flat Position	0	Degree			
Maximum-Possible Chips per Wafer	611pcs				
Passivation Frontside	Silicon Nitride				
Front Metal-Anode Pad	Al-1%Si (3μm)				
Backside Metal	Cr /Ni /Ag	Cr /Ni /Ag			
Die Bond	Electrically conductive epoxy or	Electrically conductive epoxy or solder			
Reject Ink Dot Size	0.25mm min (black, center	0.25mm min (black, center)			
Recommended Storage Environment	Store in original container, in dry N	litrogen,			
	<6 months at an ambient temperature	e of 23°C			

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**Maximum Ratings** 

	Parameter	Max.	Units
$V_{RRM}$	Reverse Voltage	1200	V
$T_{J}$ , $T_{STG}$	Operating Junction and Storage Temperature	-40 to +150	°C

Static Characteristics (Tested on wafers) . T<sub>J</sub>=25°C

	Parameter	Min.	Тур.	Max.	Units	Conditions
$V_{RRM}$	Maximum Reverse Breakdown Voltage	1200			\/	$I_{RRM}$ = 150 $\mu$ A, $T_{J}$ = 25 $^{\circ}$ C
$V_{FM}$	Maximum Forward Voltage			1.85	V	$T_J = 25^{\circ}C, I_F = 10A,$
$I_{RM}$	Maximum Reverse Leakage Current			10	μA	$T_J = 25^{\circ}C, V_{RRM} = 1200V$

**Electrical Characteristics (Not subject to production test)** 

	Parameter	Min.	Тур.	Max.	Units	TJ	Conditions
. ,			2.3	2.7	V	25°C	$I_F = 40A$ , $T_J = 25^{\circ}C$
V <sub>F</sub> Forward Voltage	Forward Voltage		2.5		<b>V</b>	150°C	I <sub>F</sub> = 40A , T <sub>J</sub> = 150°C
I <sub>R</sub>	Leakage Current		1.9		μΑ	25°C	$V_R = 1200V, T_J = 25^{\circ}C$
			1.0		mA	150°C	$V_R = 1200V, T_J = 150^{\circ}C$

Switching Characteristics (Inductive Load-Not subject to production test)

	Parameter	Min.	Тур.	Max.	Units	ΤJ	Conditions
4	Doverse Decevery Time		250	_		25°C	
t <sub>rr</sub>	Reverse Recovery Time		255	_	ns	150°C	
0	Poverse Pesevery Charge	_	3.6	_		25°C	
$Q_{rr}$	Reverse Recovery Charge	_	6.2	_	μC	150°C	
	Peak Reverse Recovery Current	_ 24 _	_	۸	25°C	$I_F = 40A$ , di/dt=400A/ $\mu$ s,	
Itt	Feak Reverse Recovery Current		38	_	Α	150°C	$V_{RR} = 600V$
_	Dayoraa Dagayary Engray	_	2.2	_	- m I	25°C	
Err	Reverse Recovery Energy		3.7	_	mJ	150°C	
	Softness (t. /t.)		2.2	_		25°C	
S	Softness (t <sub>b</sub> /t <sub>a</sub> )	_	1.2	_		150°C	

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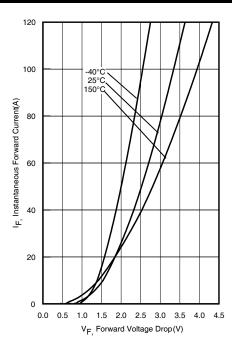


Fig 1. Typical Forward Charateristic

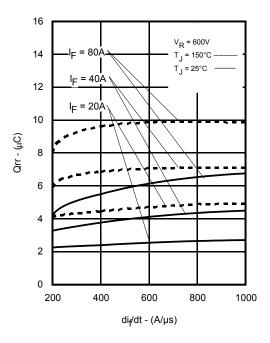


Fig 3. Typical Q<sub>rr</sub> vs. di/dt

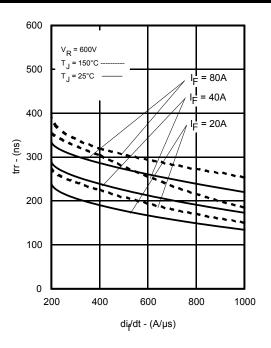


Fig 2. Typical t<sub>rr</sub> vs. di/dt

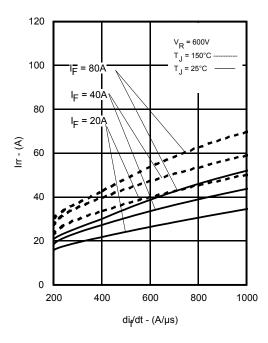


Fig 4. Typical I<sub>rr</sub> vs. di/dt

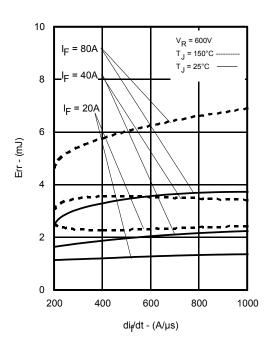


Fig 5. Typical Err vs. di/dt

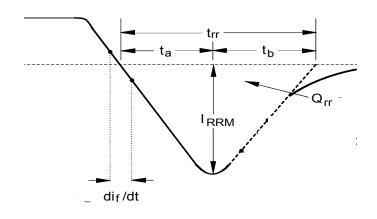
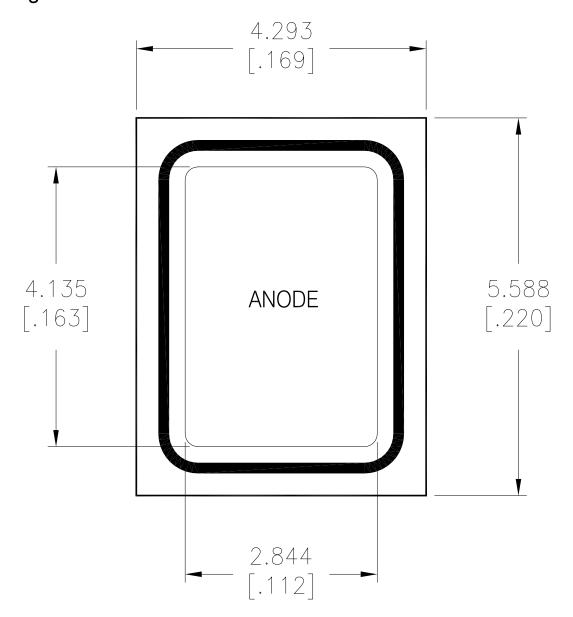


Fig 6. Reverse Recovery Waveform



# Die Drawing



### NOTES:

- 1. ALL DIMENSIONS ARE SHOWN IN MILLIMETERS [INCHES].
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. DIE WIDTH AND LENGTH TOLERANCE: + 0/ -0.0508 [+ 0/ -.002]
- 4. DIE THICKNESS = 0.330 [.013]

REFERENCE: IRD3CH24DB6



#### **Additional Testing and Screening**

For Customers requiring product supplied as Known Good Die (KGD) or requiring specific die level testing, please contact your local IR Sales.

#### **Shipping**

Three shipping options are offered.

- Un-sawn wafer
- Die in waffle pack (consult the IR Die Sales team for availability)
- Die on film (consult the IR Die Sales team for availability)

Tape and Reel is also available for some products. Please consult your local IR sales office or email <a href="http://die.irf.com">http://die.irf.com</a> for additional information.

Please specify your required shipping option when requesting prices and ordering Die product. If not specified, Un-sawn wafer will be assumed.

#### Handling

- Product must be handled only at ESD safe workstations. Standard ESD precautions and safe work environments are as defined in MIL-HDBK-263.
- Product must be handled only in a class 10,000 or better-designated clean room environment.
- Singulated die are not to be handled with tweezers. A vacuum wand with a non-metallic ESD protected tip should be used.

### Wafer/Die Storage

- Proper storage conditions are necessary to prevent product contamination and/or degradation after shipment.
- Un-sawn wafers and singulated die can be stored for up to 12 months when in the original sealed packaging at room temperature (45% +/- 15% RH controlled environment).
- Un-sawn wafers and singulated die that have been opened can be stored when returned to their containers and placed in a Nitrogen purged cabinet, at room temperature (45% +/- 15% RH controlled environment).
- Note: To reduce the risk of contamination or degradation, it is recommended that product not being used in the
  assembly process be returned to their original containers and resealed with a vacuum seal process.
- Sawn wafers on a film frame are intended for immediate use and have a limited shelf life.
- Die in Surf Tape type carrier tape are intended for immediate use and have a limited shelf life. This is primarily due to the nature of the adhesive tape used to hold the product in the carrier tape cavity. This product can be stored for up to 30 days. This applies whether or not the material has remained in its original sealed container.

#### **Further Information**

For further information please contact your local IR Sales office or email your enquiry to

http://die.irf.com



**IR WORLD HEADQUARTERS:** 101 N. Sepulveda Blvd., El Segundo, California 90245, USA To contact International Rectifier, please visit <a href="http://www.irf.com/whoto-call/">http://www.irf.com/whoto-call/</a>